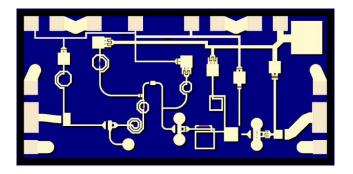


# **Applications**

- Commercial and Military Radar
- Satellite Communications



# **Functional Block Diagram**

# **Product Features**

- Frequency Range: 16 18 GHz
- NF: 2.3 dB
- Small Signal Gain: 28 dB
- Return Loss: >9 dB
- P1dB: 6 dBm
- $P_{SAT} = 10 \text{ dBm}$  at  $P_{IN} = -10 \text{ dBm}$
- OTOI: 13 dBm (Pout/tone = -2 dBm)
- Bias:  $V_D = 3 V$ ,  $I_{DQ} = 30 mA$ ,  $V_G = -0.6 V$
- Chip Dimensions: 2.1 x 1.1 x 0.1 mm

# **General Description**

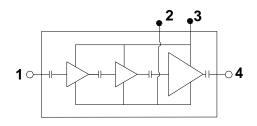
TriQuint's TGA2618 is a Ku-band Low Noise Amplifier fabricated on TriQuint's TQPHT15 0.15  $\mu$ m GaAs pHEMT process. The TGA2618 operates from 16 to 18 GHz and typically provides 6 dBm P1dB, 28 dB of small signal gain and 13 dBm OTOI with 2.3 dB NF.

The TGA2618 is ideally suited to support both radar and satellite communications as either an LNA or a general purpose gain block.

Both RF ports have intergraded DC blocking caps and are fully matched to 50 ohms allowing for simple system integration.

Lead-free and RoHS compliant

Evaluation Boards are available upon request.



# Pad Configuration

Pad No.	Symbol
1	RFIN
2	V <sub>G</sub>
3	VD
4	RFout

Ordering Information					
Part	ECCN	Description			
TGA2618	EAR99	16 - 18 GHz GaN LNA			

# Absolute Maximum Ratings

Parameter	Value
Drain Voltage (V <sub>D</sub> )	6 V
Gate Voltage Range (V <sub>G</sub> )	-2 to 0 V
Drain Current (I <sub>D</sub> )	70 mA
Gate Current (I <sub>G</sub> )	-0.5 to 6 mA
Power Dissipation, 85 °C (PDISS)	0.3 W
Input Power, CW, 50 $\Omega$ , (P <sub>IN</sub> )	0 dBm
Channel temperature (TCH)	200 °C
Mounting Temperature (30 Seconds)	320 °C
Storage Temperature	-55 to 150 °C

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied.

## **Recommended Operating Conditions**

Parameter	Value
Drain Voltage (V <sub>D</sub> )	3 V
Drain Current (I <sub>DQ</sub> )	30 mA
Gate Voltage (V <sub>G</sub> )	-0.6 V Typical
Temperature (T <sub>BASE</sub> )	-40 to 85 °C

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed overall operating conditions.

# **Electrical Specifications**

Parameter	Min	Typical	Max	Units
Operational Frequency Range	16		18	GHz
Small Signal Gain		28		dB
Noise Figure		2.3		dB
Input Return Loss		>9		dB
Output Return Loss		>10		dB
Output Power at 1 dB Gain Compression		6		dBm
Output TOI at Pout/tone = -2 dBm		13		dBm
Gain Temperature Coefficient		-0.03		dB/°C
Noise Figure Temperature Coefficient		0.007		dB/°C

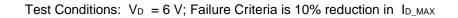


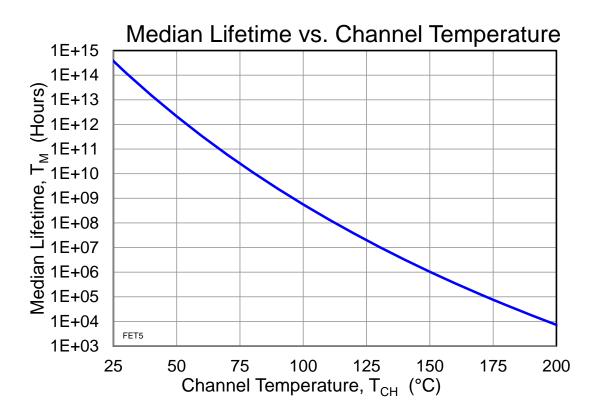
# **Thermal and Reliability Information**

Parameter	Test Conditions	Value	Units
Thermal Resistance ( $\theta_{JC}$ ) <sup>(1)</sup>	T 05 00 M 0 M (0 M)	96	°C/W
Channel Temperature (T <sub>CH</sub> ) (Without RF)	$T_{base} = 85 \text{ °C}, V_D = 3 \text{ V} (CW)$ $I_{DQ} = 30 \text{ mA}, P_{DISS} = 0.09 \text{ W}$	94	°C
Median Lifetime (T <sub>M</sub> )		1.3 x 10^9	Hrs
		·	
Thermal Resistance (θ <sub>JC</sub> ) <sup>(1)</sup>	$T_{base} = 85 \ ^{\circ}C, V_{D} = 3 \ V \ (CW)$	96	°C/W
Channel Temperature (T <sub>CH</sub> ) (Under RF drive)	<ul> <li>I<sub>DQ</sub> = 30 mA, I<sub>D_Drive</sub> = 50 mA</li> <li>P<sub>IN</sub> = -10 dBm, POUT = 10 dBm,</li> </ul>	98	°C
Median Lifetime (T <sub>M</sub> )	Freq = 17 GHz, $P_{DISS} = 0.14$ W	7.5 x 10^8	Hrs

#### Notes:

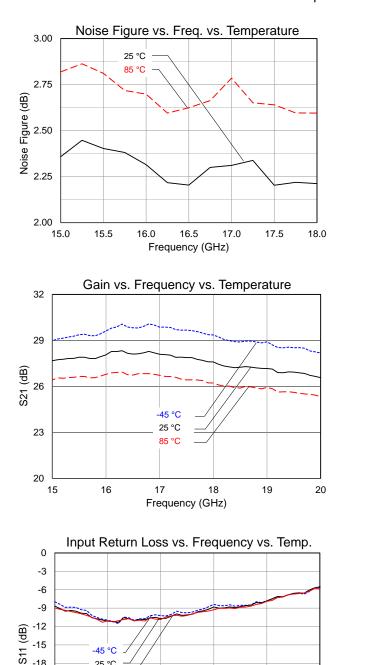
1. Thermal resistance calculated at back of a 40 mil CuMo carrier plate with 1.5 mil of AuSn solder for die attach.

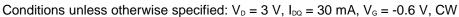


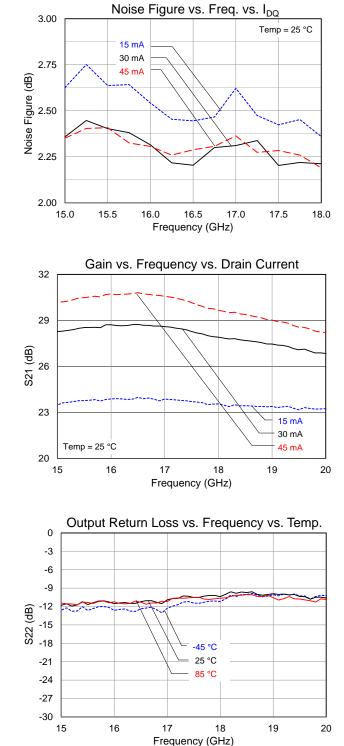




# **Typical Performance: Small Signal**







Preliminary Datasheet: Rev - 09-09-14 © 2014 TriQuint

16

17

Frequency (GHz)

18

19

20

-45 °C

25 °C

85 °C

-18

-21

-24

-27

-30

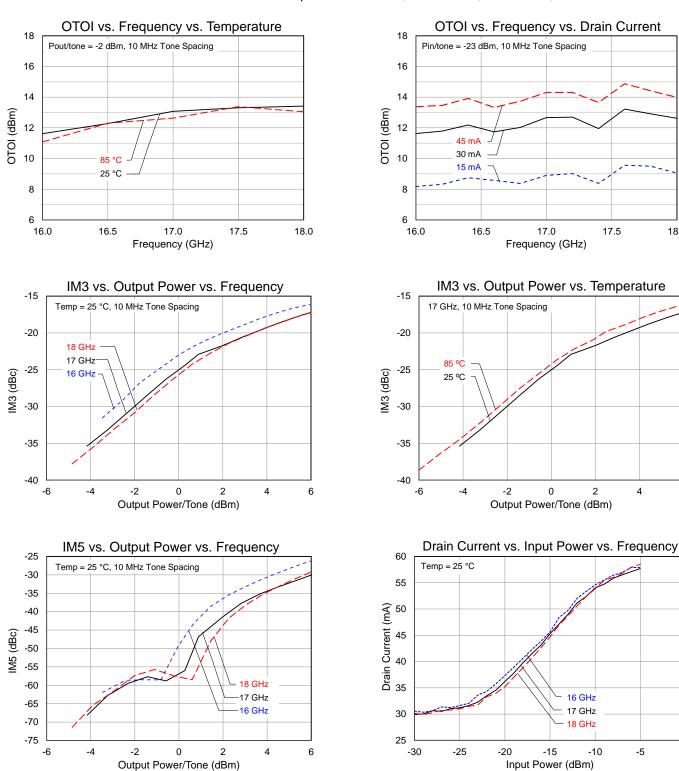
15



18.0

17.5

# **Typical Performance: Linearity**



Conditions unless otherwise specified:  $V_D = 3 \text{ V}$ ,  $I_{DQ} = 30 \text{ mA}$ ,  $V_G = -0.6 \text{ V}$ , CW

-10

16 GHz

17 GHz

18 GHz

-15

0

2

4

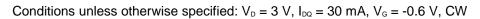
-5

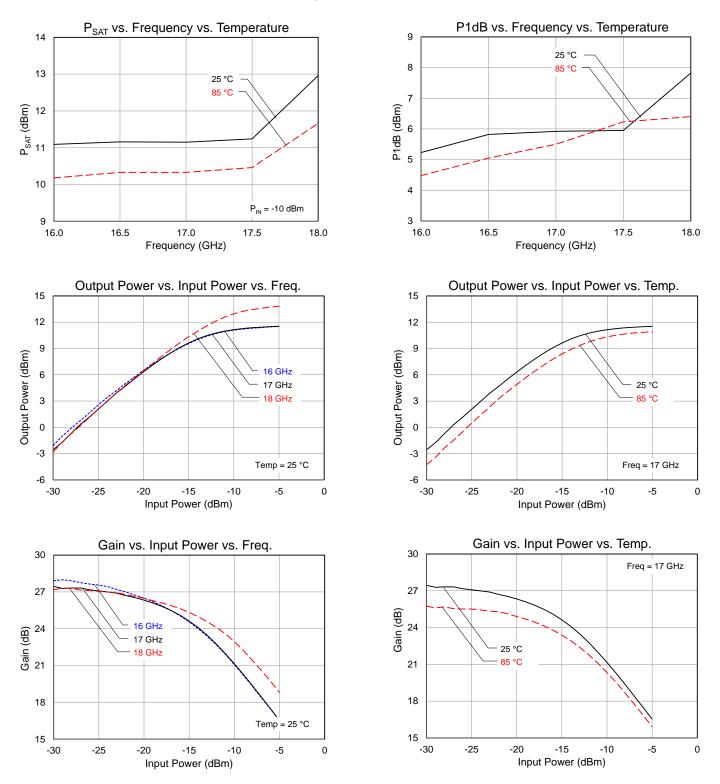
0

6



# **Typical Performance: Large Signal**

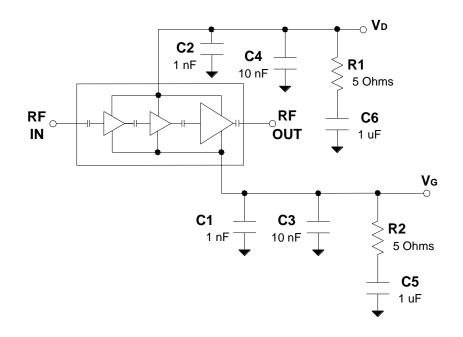




Preliminary Datasheet: Rev - 09-09-14 © 2014 TriQuint



# **Application Information**



#### **Bias-up Procedure**

- 1. Set  $I_D$  limit to 70 mA,  $I_G$  limit to 6 mA
- 2. Apply -2 V to V<sub>G</sub> for pinch off
- 3. Apply +3 V to V<sub>D</sub>
- 4. Adjust V<sub>G</sub> more positive until  $I_{DQ}$  = 30 mA (V<sub>G</sub> ~ -0.6 V Typical)

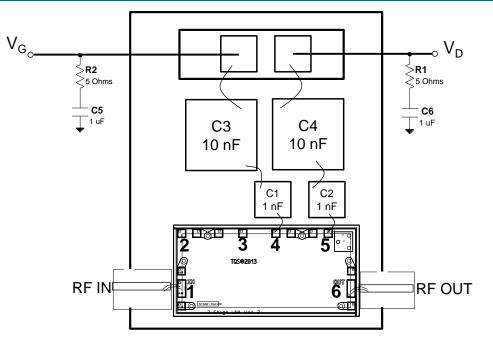
5. Apply RF signal

#### **Bias-down Procedure**

- 1. Turn off RF signal
- 2. Reduce V<sub>G</sub> to -2V. Ensure  $I_{DQ} \sim 0mA$
- 3. Set  $V_{\text{D}}$  to 0V
- 4. Turn off V<sub>D</sub> supply
- 5. Turn off V<sub>G</sub> supply



# **Assembly Drawing**

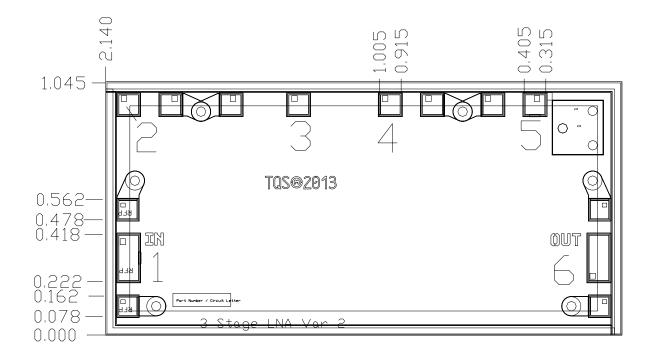


# **Bill of Material**

Reference Des.	Value	Description	Manuf.	Part Number
C1, C2	1 nF	Single-layer ceramic capcitor	Various	
C3, C4	10 nF	Single or multi-layer ceramic capacitor (may also use 0.01 µF SMT capacitors)	Various	
C5, C6	1 µF	1206 SMT Capacitor	Various	
R1, R2	5 Ohms	SMT Resistor	Various	



# **Mechanical Information**



Units: millimeters Thickness: 0.10 Die x,y size tolerance:  $\pm$  0.050 Ground is backside of die RF<sub>IN</sub> and RF<sub>OUT</sub> pads are symmetric

Pad Description					
Pad No.	Symbol	Description	Pad Size		
1	RFIN	Input; matched to 50 $\Omega$ ; DC blocked	0.205 x 0.1 mm		
2,3	N/C	Do not connect	0.1 x 0.1 mm		
4	Vg	Gate voltage; bias network is required; see recommended Application	0.1 x 0.1 mm		
5	VD	Drain voltage; bias network is required; see recommended Application	0.1 x 0.1 mm		
6	RFout	Output; matched to 50 Ω; DC blocked	0.205 x 0.1 mm		

# TriQuint

# **Assembly Notes**

Component placement and adhesive attachment assembly notes:

- Vacuum pencils and/or vacuum collets are the preferred method of pick up.
- Air bridges must be avoided during placement.
- The force impact is critical during auto placement.
- Organic attachment (i.e. epoxy) can be used in low-power applications.
- Curing should be done in a convection oven; proper exhaust is a safety concern.

Solder attachment reflow process assembly notes:

- Use AuSn (80/20) solder and limit exposure to temperatures above 300°C to 3 to 4 minutes, maximum.
- An alloy station or conveyor furnace with reducing atmosphere should be used.
- Do not use any kind of flux.
- Coefficient of thermal expansion matching is critical for long-term reliability.
- Devices must be stored in a dry nitrogen atmosphere.

Organic adhesive attachment assembly notes:

- Organic adhesives such as ABLEBOND 84-1, or equivalent, can be used.
- Epoxies cure at temperatures of 100 to 200°C.

Interconnect process assembly notes:

- Thermosonic ball bonding is the preferred interconnect technique.
- Force, time, and ultrasonics are critical parameters.
- Aluminum wire should not be used.
- Devices with small pad sizes should be bonded with 0.0007-inch wire.



## **Product Compliance Information**

# **ESD Sensitivity Ratings**



Caution! ESD-Sensitive Device

ESD Rating: TBD Value: TBD Test: Human Body Model (HBM) Standard: JEDEC Standard JESD22-A114

## **RoHS-Compliance**

This part is compliant with EU 2002/95/EC RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment).

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C<sub>15</sub>H<sub>12</sub>Br<sub>4</sub>0<sub>2</sub>) Free
- PFOS Free
- SVHC Free

# **MSL** Rating

Level TBD at TBD°C convection reflow The part is rated Moisture Sensitivity Level TBD at TBD°C per JEDEC standard IPC/JEDEC J-STD-020.

## ECCN

US Department of Commerce: EAR99

#### **Contact Information**

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